

Infrared detector modules with preamp



Thermoelectrically cooled types

Easy-to-use detector modules with built-in preamps

Infrared detector modules operate just by connecting to DC power supplies. Low noise thermoelectric cooled types using InGaAs, InAs or InAsSb elements are available. We welcome requests for custom devices that suit your application.

- Features

- High S/N
- Compact size
- Easy to use Operates just by connecting to DC power supply
- □ Circuit design optimized for detector characteristics
- Built-in temperature control circuit (TE-cooled type)

Applications

Infrared detection

Accessories

- 6-conductor cable for TE-cooled type (for DC power supply): 2 m (with one side connector) A4372-07
- **■** Instruction manual

Structure

	Detector element	Cooling		Photosensitive	Supply voltage	
Type no.			Window material	area	Vcc*1	V p*1
				(mm)	(V)	(V)
C12483-250	InGaAs (G12180-250A)		AR coated (1.55 µm peak) borosilicate glass	ф5	±15 ± 0.5	+2.5 ^{+0.5} _{-0.1}
C12485-210	InGaAs (G12182-210K)		Dorosilianto alpas	ф1		
C12486-210	InGaAs (G12183-210K)	l	Borosilicate glass			
C12492-210	InAs (P10090-21)	Two-stage TE-cooled	Sapphire glass			
C12494-222S NEW	InAsSb (P13243-222MS)	i E-cooled		2 × 2		
C12494-210S	InAsSb (P11120-201)			h1	5	
C12494-210M	InAsSb (P12691-201G)		AR coated Ge	ф1		
C12494-211L	InAsSb (P13894-211MA)			1 × 1		

^{*1:} Vcc=power supply for circuit, Vp=power supply for cooling



→ Absolute maximum ratings

"	Incident light level	Supply	voltage	Operating temperature*2	Storage temperature*2 Tstg (°C)	
Type no.	(μW)	Vcc (V)	Vp (V)	Topr (°C)		
C12483-250	0.2				-	
C12485-210	0.06					
C12486-210	0.07					
C12492-210	2.6	110	+5	0 to 140	-20 to +50	
C12494-222S NEW	14 mW	±18	+3	0 to +40	-20 (0 +50	
C12494-210S	26					
C12494-210M	∠0					
C12494-211L	28 mW					

^{*2:} No dew condensation

When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

■ Optical characteristics (Typ. Ta=25 °C, unless otherwise noted)

Туре по.	Chip temperature at rated supply voltage	Peak sensitivity wavelength λp (μm)	Cutoff wavelength λc (μm)	Photosensitivity*³ S λ=λp		Noise equivalent power NEP λ=λp	
	Tchip (°C)			Min. (V/W)	Typ. (V/W)	Typ. (W/Hz ^{1/2})	Max. (W/Hz ^{1/2})
C12483-250	-15	1.55	1.66	3.3×10^{7}	5.8×10^{7}	5.2 × 10 ⁻¹⁴	7 × 10 ⁻¹³
C12485-210		1.95	2.05	1.1×10^{8}	1.8×10^{8}	1 × 10 ⁻¹³	3 × 10 ⁻¹²
C12486-210		2.3	2.56	1 × 10 ⁸	2 × 10 ⁸	4 × 10 ⁻¹³	6 × 10 ⁻¹²
C12492-210	-28	3.25	3.45	0.8×10^{7}	1×10^{7}	6 × 10 ⁻¹²	1 × 10 ⁻¹¹
C12494-222S NEW		4.1	5.1	5 × 10 ²	7×10^{2}	8 × 10 ⁻¹⁰	1.2 × 10 ⁻⁹
C12494-210S		4.9	5.9	5 × 10 ⁵	7.5 × 10⁵	1 × 10 ⁻¹⁰	3 × 10 ⁻¹⁰
C12494-210M		6.7	8.3				2 × 10
C12494-211L		5.6	10.2	2.5 × 10 ^{2*4}	3.5 × 10 ^{2*4}	1.5 × 10 ⁻⁹	4.5 × 10 ⁻⁹

^{*3:} f=100 Hz (C12483-250, C12485-210, C12486-210), f=1.2 kHz (C12492-210, C12494-210S/-210M), f=600 Hz (C12494-211L/-222S)

■ Electrical characteristics (Typ. Ta=25 °C, unless otherwise noted)

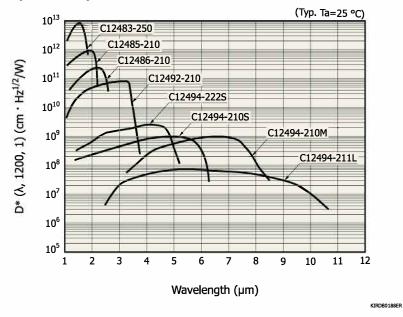
Type no.	Frequency response -3 dB		Output impedance	Maximum output voltage RL=1 kΩ	Current consumption*5				
	(Hz)				Vcc		Vp		
	FcL FcH				Тур.	Max.	Тур.	Max.	
	Тур.	Min.	Тур.	(Ω)	(V)	(mA)	(mA)	(mA)	(mA)
C12483-250	DC	900	1.1 k	50		+30 -13	+50, -30	+500	
C12485-210	DC	1.5 k	2.2 k		+10		+60, -30		
C12486-210	DC	2.1 k	3 k					3	
C12492-210	5	40 k	50 k		±13		+30, -20 +80, -30	+600	+1100
C12494-222S NEW	DC	750 k	1 M		+10	+30, -20			
C12494-210S	5	80 k	100 k	ľ	±13				
C12494-210M	J	00 K	100 K						
C12494-211L	DC	750 k	1 M		+10			+500	

^{*5:} Vcc=±15 V, Vp=2.5 V (C12485-210, C12486-210, C12483-250, C12492-210, C12494-210S/-222S/-210M/-211L)
Recommended DC power supply (analog power supply): PW18-1.3ATS (TEXIO Technology), E3630A (Keysight Technologies)
Current capacity: More than 1.5 times the maximum current consumption
Ripple noise: 5 mVp-p or less (±15 V, +2.5 V power supply)



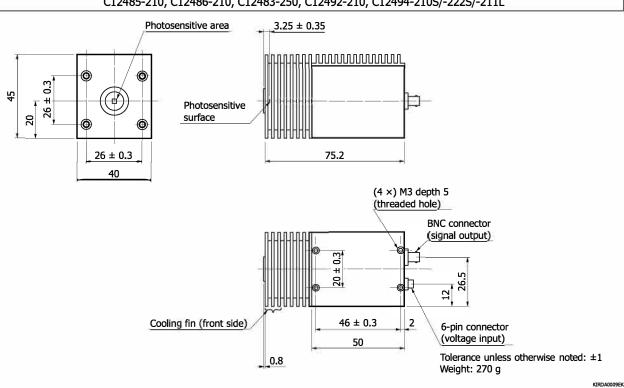
^{*4:} Uniform irradiation on the entire photosensitive area.

Spectral response

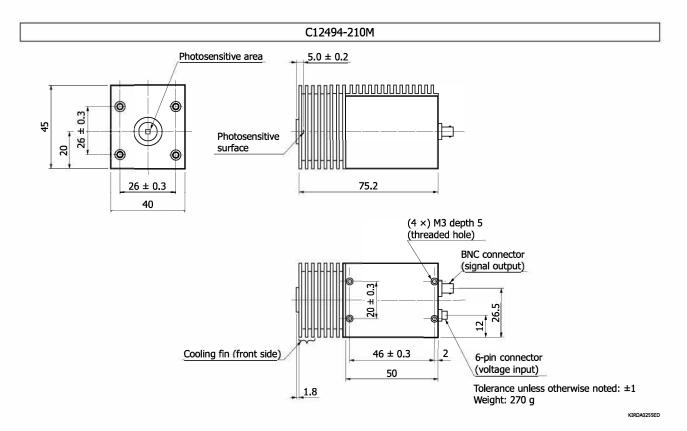


Dimensional outlines (unit: mm)

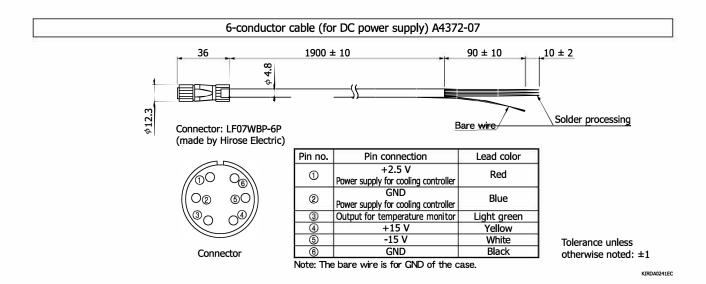
C12485-210, C12486-210, C12483-250, C12492-210, C12494-210S/-222S/-211L







Note: The cooling fin (front side) is removable.





Infrared detect or modules with preamp

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Precautions

- · Always use a dual-polarity ±15 V or ±2.5 V power supply to operate this detector. Never use a single-polarity power supply. Using a single-polarity power supply may cause the amplifier in the detector module to break down.
- · Regarding TE-cooled type, always supply +2.5 V to cool the detector element.
- · Be careful not to apply excessive force to the detector surface. Applying excessive force may damage the light input window. Do not directly touch the light input window with bare hands. If dust or dirt gets on the window, wipe it gently using ethyl alcohol.
- Do not drop this product or do not apply excessive shock to it.

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
- Disclaimer
- Safety consideration
- Compound opto-semiconductors (photosensors, light emitters)
- Technical note
- · Compound semiconductor photosensors



www.boselec.com | shop.boselec.com tel: 617-566-3821 | boselec@boselec.com

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AMAMATSU

www.hamamatsu.com

HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Higashi-ku, Hamamatsu City, 435-8558 Japan, Telephone: (81)53-434-3311, Fax: (81)53-434-5184

LICA: HOMANISTU CORPORTION: 360 Foothill Road, Bridgewater, NJ 08807, U.S.A.; Telephone: (1)908–259-11-218
Germany: HAWAMATSU CORPORTION: 360 Foothill Road, Bridgewater, NJ 08807, U.S.A.; Telephone: (1)908–259-11-218
Germany: HAWAMATSU PHOTONICS DEUTSCHLAND GMBH: Arzbergerstr. 10, 82211 Herrsching am Ammersee, Germany, Telephone: (4)98152-375-0, Fax: (4)9152-265-8 E-mail: info@hamamatsu.de
France: HAWAMATSU PHOTONICS GRANCE S.A.R.L.: 19 Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Codex, France, Telephone: (33)1 69 53 71 00, Fax: (33)1 69 53 71 10 Famil: info@hamamatsu.de
United Kingdom: HAWAMATSU PHOTONICS UK LIMITED: 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire, AJ. 7 18W, UK, Telephone: (4)1707-294888, Fax: (4)1707-325777 E-mail: info@hamamatsu.co.uk
North Europe: HAMAMATSU PHOTONICS INCEN AB: Torshamisquata 75, 16440 Kista, Sweden, Telephone: (39)02-93 58 17 33, Fax: (39)02-93 58 17 41 E-mail: info@hamamatsu.se
Taily: HAMAMATSU PHOTONICS (CHINA) CO., LTD:: 1201, Tower B, Jiaming Center, 72 Drogsanhuan Bellu, Chaoayang District, 100020 Beljing, RR. China; Telephone: (6)010-6586-2866 E-mail: hpc@hamamatsu.co
Taiwan: HAMAMATSU PHOTONICS TAIWAN CO., LTD:: 1201, Tower B, Jiaming Center, 72 Drogsanhuan Bellu, Chaoayang District, 100020 Beljing, RR. China; Telephone: (6)010-6586-0960. Fax: (6)10-6596-0960. Fax: (6